



Appl. No. 09/920,978

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No.09/920,978
Filing DateAugust 1, 2001
Inventor..... Shane J. Trapp
Assignee..... Micron Technology, Inc.
Group Art Unit.....2813
Examiner Blum, David S.
Attorney's Docket No.MI22-1674
Title: Method of Forming Integrated Circuitry and Method of Forming Shallow Trench
Isolation in a Semiconductor Substrate

RESPONSE TO SEPTEMBER 24, 2003 FINAL OFFICE ACTION TO ACCOMPANY RCE

To: MS RCE
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

From: Jennifer J. Taylor, Ph.D. (Tel. 509-624-4276; Fax 509-838-3424)
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AMENDMENTS

Introductory Comments

In reply to the Office Action of September 24, 2003, applicant amends and remarks
as follows.

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TECHNOLOGY CENTER 2800